Preferred Device

Amplifier Transistors

PNP Silicon

Features

Pb-Free Packages are Available*



Rating	Symbol	2N5400	2N5401	Unit
Collector - Emitter Voltage	V _{CEO}	120	150	Vdc
Collector - Base Voltage	V _{CBO}	130	160	Vdc
Emitter - Base Voltage	V _{EBO}	5.0		Vdc
Collector Current - Continuous	Ic	600		mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0		mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	1.5 12		Watts mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150		°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

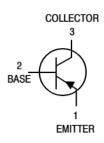
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	R _{0JA}	200	°C/W
Thermal Resistance, Junction-to-Case	R _{0JC}	83.3	°C/W



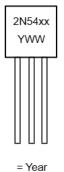
ON Semiconductor®

http://onsemi.com





MARKING DIAGRAM



WW = Work Week

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Preferred devices are recommended choices for future use and best overall value.

2N5401

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS				•	
Collector-Emitter Breakdown Voltage ⁽¹⁾ (I _C = 1.0 mAdc, I _B = 0)	2N5400 2N5401	V _(BR) CEO	150	-	Vdc
Collector-Base Breakdown Voltage (I _C = 100 μAdc, I _E = 0)	2N5400 2N5401	V _(BR) CBO	160	_	Vdc
Emitter-Base Breakdown Voltage $(I_E = 10 \mu Adc, I_C = 0)$		V _{(BR)EBO}	5.0	-	Vdc
Collector Cutoff Current (V _{CB} = 120 Vdc, I _E = 0) (V _{CB} = 120 Vdc, I _E = 0, T _A = 100°C)	2N5401 2N5401	Ісво	- -	50 50	
Emitter Cutoff Current (V _{EB} = 3.0 Vdc, I _C = 0)		I _{EBO}	-	50	nAdc
ON CHARACTERISTICS (Note 1)				•	
DC Current Gain (I_C = 1.0 mAdc, V_{CE} = 5.0 Vdc) (I_C = 10 mAdc, V_{CE} = 5.0 Vdc) (I_C = 50 mAdc, V_{CE} = 5.0 Vdc)		h _{FE}	50 60 50	- 240 -	-
Collector-Emitter Saturation Voltage (I _C = 10 mAdc, I _B = 1.0 mAdc) (I _C = 50 mAdc, I _B = 5.0 mAdc)		V _{CE(sat)}	- -	0.2 0.5	Vdc
Base-Emitter Saturation Voltage ($I_C = 10 \text{ mAdc}$, $I_B = 1.0 \text{ mAdc}$) ($I_C = 50 \text{ mAdc}$, $I_B = 5.0 \text{ mAdc}$)		V _{BE(sat)}	- -	1.0 1.0	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current-Gain — Bandwidth Product (I _C = 10 mAdc, V _{CE} = 10 Vdc, f = 100 MHz)		f _T	100	300	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 1.0 MHz)		C _{obo}	-	6.0	pF
Small-Signal Current Gain (I _C = 1.0 mAdc, V _{CE} = 10 Vdc, f = 1.0 kHz)		h _{fe}	40	200	-
Noise Figure (I _C = 250 μ Adc, V _{CE} = 5.0 Vdc, R _S = 1.0 k Ω , f = 1	1.0 kHz)	NF	-	8.0	dB

^{1.} Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

ORDERING INFORMATION

Device	Package	Shipping [†]	
2N5401	TO-92	5000 Unit / Bulk	
2N5401RL1	TO-92	2000 Tape & Reel	
2N5401RLRA	TO-92	2000 Tape & Reel	
2N5401RLRAG	TO-92 (Pb-Free)	2000 Tape & Reel	
2N5401RLRM	TO-92	2000 Tape & Ammo Box	
2N5401ZL1	TO-92	2000 Tape & Ammo Box	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

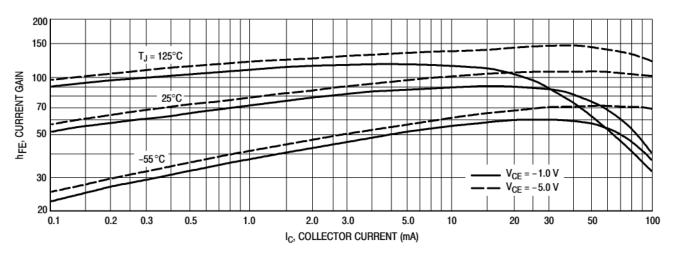


Figure 1. DC Current Gain

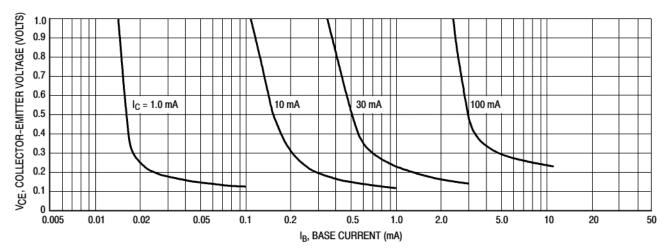


Figure 2. Collector Saturation Region

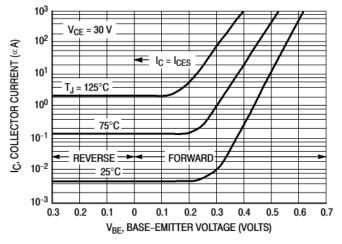


Figure 3. Collector Cut-Off Region

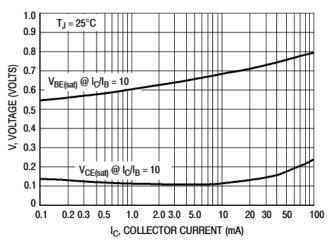


Figure 4. "On" Voltages

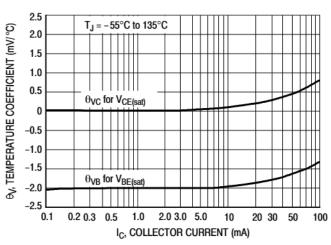
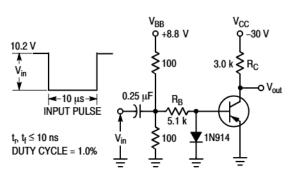


Figure 5. Temperature Coefficients



Values Shown are for I_C @ 10 mA

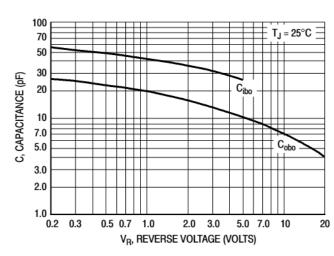


Figure 7. Capacitances

Figure 6. Switching Time Test Circuit

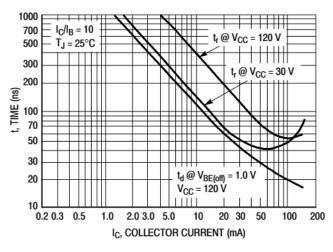


Figure 8. Turn-On Time

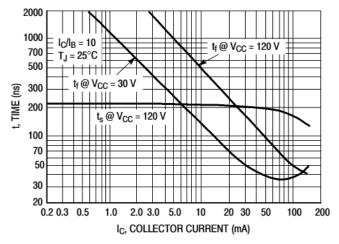
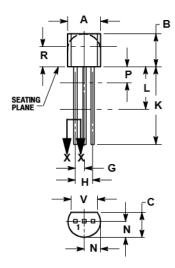


Figure 9. Turn-Off Time

PACKAGE DIMENSIONS

TO-92 CASE 29-11 ISSUE AL





NOTES:

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: INCH.

 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.

 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	

- STYLE 1: PIN 1. EMITTER

 - BASE
 COLLECTOR

2N5401

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